

PC28F640P30BF65A Micron Technology Inc Product Details PDF





Images are for reference See Product Specification













Part Number: PC28F640P30BF65A

EOLSEMI Part: PC28F640P30BF65A-25567

Category: FLASH

Manufacturer: Micron Technology Inc

Applications: ■Aerospace & defense ■Test & measurement

■Automotive ■Communications equipment ■Industrial

Description: IC FLASH 64M PARALLEL 64EASYBGA

Lead free / RoHS Compliant **RoHS:**

Stock Category: In stock

Stock Resource: Franchised Distributor

Warranty: 1 Year Guarantee » Learn More

EDA/CAD Models: PC28F640P30BF65A PCB Footprint and Symbol

Delivery:

Payment: PayPai VISA 🍩 T/T WESTESS WU

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JS28F00AP33TFA - Micron Technology Inc. - FLASH

IC FLASH 1G PARALLEL 56TSOP

JS28F256P30TF - Intel Corporation - FLASH

Flash, 16MX16, 88ns, PBGA64

<u>K3PE7E700D-XGC2</u> - <u>Samsung Electro-Mechanics</u> - <u>DRAM</u>

MOBILE DRAM, LPDDR2, 8GB, FBGA-220

K4B1G1646G-BCH9 - Samsung Electronics Co. Ltd - DRAM

DDR DRAM, 64MX16, 0.255NS, CMOS, PBGA96

K4B2G1646C-HCH9 - Samsung Electronics Co. Ltd - DRAM

128M X 16 DDR DRAM, 0.255 ns, PBGA96

K4B2G1646Q-BCK0 - Samsung Electro-Mechanics - DRAM

DDR DRAM, 128MX16, 0.225NS, CMOS, PBGA96

K4H561638F-UCB3 - Samsung Semiconductor - DRAM

SDRAM, DDR, 16M x 16, 66 Pin, Plastic, TSSOP

K4M561633G-BN75 - Samsung Electro-Mechanics - DRAM

SYNCHRONOUS DRAM, 16MX16, 5.4NS, CMOS, PBGA54

<u>K4P4G324EB-AGC1</u> - <u>Samsung Semiconductor</u> - <u>DRAM</u>

DRAM Chip Mobile LPDDR2 SDR 4G-Bit 128Mx32 1.2V 168-Pin FBGA - Trays

<u>K4P8G304EB-FGC1</u> - <u>Samsung Electro-Mechanics</u> - <u>DRAM</u>

MOBILE DDR2-S4 SDRAM MEMORY, 1GB X 32, 400MHZ, FBGA134

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